# NSN 5961-01-148-0179

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#### Inclosure Material:

Metal

## **Overall Length:**

Between 1.553 inches and 1.573 inches

# **Overall Height:**

0.762 inches

#### **Overall Width:**

1.050 inches

#### **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

#### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

450.0 collector to base voltage/static/emitter open and 400.0 collector to emitter voltage/static/base open

#### **Current Rating Per Characteristic:**

Between 10.00 amperes source cutoff current and 20.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 pin and 1 case

#### Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

# Fiig:

A110a0